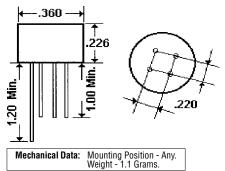
2.0 Amp SINGLE PHASE SILICON BRIDGE

Description



Mechanical Dimensions



Features

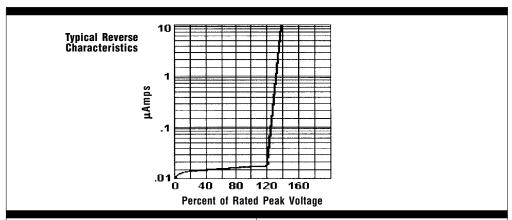
- COMPACT SIZE
- LOW LEAKAGE CURRENT

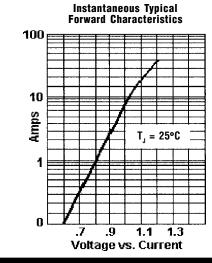
- 200 AMP SURGE OVERLOAD RATING
- MEETS UL SPECIFICATION 94V-0

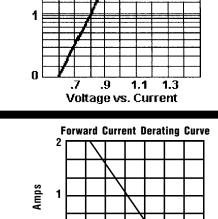
Electrical Characteristics @ 25°C.	2W005 10 Series							Units
Maximum Ratings	2W005	2W01	2W02	2W04	2W06	2W08	2W10	
Peak Repetitive Reverse VoltageV _{RRM}	50	100	200	400	600	800	1000	Volts
RMS Reverse VoltageV _{R(rms)}	35	70	140	280	420	560	700	Volts
DC Blocking VoltageV _{DC}	50	100	200	400	600	800	1000	Volts
Average Forward Rectified Current $I_{F(av)}$ $T_A = 25^{\circ}C$. 2.0				Amp
Non-Repetitive Peak Forward Surge CurrentI _{FSM} 8.3 mS Single ½ Sine Wave Imposed on Rated Load				. 60				Amp
Forward VoltageV _F Bridge Element @ 2.0 Amps				1.0				Volt
DC Reverse CurrentI _R @ Rated DC Blocking Voltage $T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$								μΑm; mAm
Operating & Storage Temperature Range T_{J} , T_{STRG}				55 to 125				°C



2.0 Amp SINGLE PHASE SILICON BRIDGE

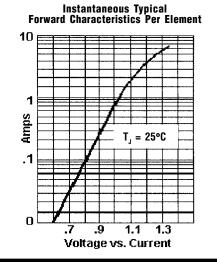


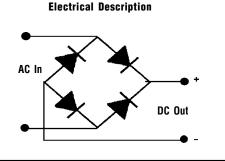




100

Ambient Temperature (°C)





Ratings at 25 Deg. C ambient temperature unless otherwise specified.

Single Phase Half Wave, 60 HZ Resistive or Inductive Load.

For Capacitive Load, Derate Current by 20%.